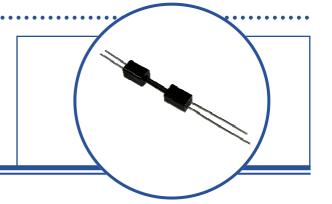
Axial Fiber Optic Isolator OP1270 Series



Features:

- Opaque plastic housings
- High noise immunity
- Visible Red LED with Phototranisitor Output
- 0.05" (1.27 mm) lead spacing
- Data Transfer through plastic fiber optic cable



Description:

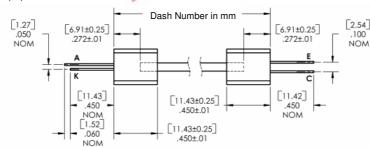
Each **OPI1270** consists of a visible Red LED and a Phototransistor sensor, which are housed in separate opaque molded plastic housings and coupled by plastic fiber optic cable. The heavy-duty opaque housing shields the optical signal from dust, making this series of devices ideal for dust contaminated environments.

The OPI1270 series are designed for applications that require high voltage isolation between input and output. Depending on the length of the fiber optic cable, the emitter does not have to be optically in-line with the sensor.

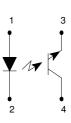
Custom electrical, wire and cabling and connectors are available. Contact your local representative or OPTEK for more information.

Applications:

- Requiring High Voltage isolation between input and output
- Electrical isolation in dirty environments
- Industrial equipment
- Medical equipment
- Office equipment



Ordering Information							
Part Number	Device Length	LED Peak Wavelength	Lead Length				
OPI1270-032	32mm (1.26")		0.45" (11.4 mm)				
OPI1270-040	40mm (1.57")	645 nm					
OPI1270-080	80mm (3.15")						



Pin #	LED	Pin #	Transistor	
1	Anode	3	Emitter	
2	Cathode	4	Collector	



DIMENSIONS ARE IN INCHES AND [MILLIMETERS].

[9.53±0.25] .375±.01

[9.53±0.25] .375±.01

OPTEK reserves the right to make changes at any time in order to improve design and to supply the best product possible.



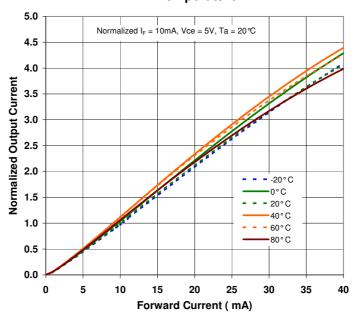
Storage	-40° C to $+100^{\circ}$ C							
Operatir	-20°C to +85°C							
Lead So	260 ° C ⁽¹⁾							
Power D		100 mW						
Electrica	al Characteristics ($T_A = 25 ^{\circ}$ C unless	ess otl	nerwise	noted)		·		
SYMBOL	PARAMETER	MIN	ΤΥΡ	МАХ	UNITS	TEST CONDITIONS		
LED (see (OVLAS6CB8 for additional information)							
V_{F}	On-State Collector Current	0.9	-	1.5	V	I _F = 20 mA		
I _R	Collector-Dark Current	-	-	80	μA	V _R = 3.0 V		
SENSOR-	-Phototransistor (See OP506 for addi	tional ir	nformatio	on)		a		
I _{CEO}	Collector Dark Current	-	-	50	nA	V _{CE} = 10 V, E _E = 0		
$V_{(BR)CEO}$	Collector-Emitter Breakdown Voltage	33	-		V	$I_{\rm C} = 100 \mu {\rm A}, {\rm E}_{\rm E} = 0$		
$V_{(BR)ECO}$	Emitter-Collector Breakdown Voltage	5.5	-	136	V	$I_{E} = 100 \ \mu A, E_{E} = 0$		
COUPLED					-0-			
I _{C(ON)}		0.36			mA	$V_{CE} = 5 \text{ V}, I_F = 10 \text{ mA}$		
$I_{ISO}^{(3)}$				1.0	μA	I @ 7 KV RMS, 25° C, Test Duration = 2 sec.		

Notes:

1. RMA flux is recommended. Duration can be extended to 10 seconds maximum when flow soldering. A maximum 20 grams force may be applied to the leads when soldering.

2. Derate linearly 1.33 mW/°C above 25°C.

3. Isolation voltage testing is required.



Output Current vs Forward Current vs Temperature

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